

3.3V CMOS 1-TO-4 CLOCK DRIVER

IDT74FCT38074

FEATURES:

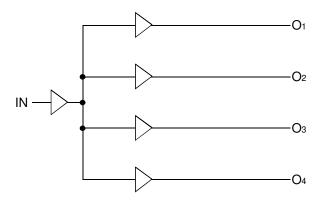
- Advanced CMOS Technology
- Guaranteed low skew < 100ps (max.)
- Very low duty cycle distortion< 250ps (max.)
- High speed propagation delay< 3ns (max.)
- · Very low CMOS power levels
- TTL compatible inputs and outputs
- 1:4 fanout
- Maximum output rise and fall time < 1.5ns (max.)
- Low input capacitance: 3pF typical
- VCC = $3.3V \pm 0.3V$
- · Inputs can be driven from 3.3V or 5V components
- Operating frequency up to 166MHz
- Available in SOIC package

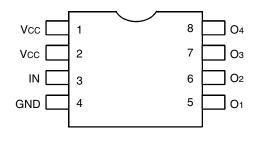
FUNCTIONAL BLOCK DIAGRAM

DESCRIPTION:

The FCT38074 is a 3.3V clock driver built using advanced CMOS technology. This low skew clock driver offers 1:4 fanout. The large fanout from a single input reduces loading on the preceding driver and provides an efficient clock distribution network. Multiple power and grounds reduce noise. Typical applications are clock and signal distribution.

PIN CONFIGURATION





SOIC TOP VIEW

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MAY 2010

INDUSTRIAL TEMPERATURE RANGE

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
Vcc	Input Power Supply Voltage	-0.5 to +4.6	V
Vi	Input Voltage	-0.5 to +5.5	V
Vo	Output Voltage	-0.5 to Vcc+0.5	V
TJ	Junction Temperature	150	°C
Tstg	StorageTemperature	-65 to +165	°C

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (TA = $+25^{\circ}C$, f = 1.0MHz)

CIN Input Capacitance VIN = 0V 3 4	0
	pF
COUT Output Capacitance VOUT = 0V — 6	pF

NOTE:

1. This parameter is measured at characterization but not tested.

PIN DESCRIPTION

Pin Names	Description
IN	Input
Ox	Outputs

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Con	ditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
lccq	Quiescent Power Supply Current	Vcc = Max.	VIN = GND or VCC	—	0.1	30	μA
Δlcc	Power Supply Current per Input HIGH	Vcc = Max.	VIN = VCC - 0.6V	_	45	300	μA
ICCD	Dynamic Power Supply Current	Vcc = Max.	VIN = VCC	_	80	120	μA/MHz
	perOutput ⁽³⁾	C∟ = 15pF	VIN = GND				
		All Outputs Toggling					
lc	Total Power Supply Current ⁽⁴⁾	Vcc = Max.	VIN = VCC		80	110	
		C∟ = 15pF	VIN = GND				
		All Outputs Toggling	VIN = VCC -0.6V		80	110	1
		fi = 133MHz	VIN = GND				mA
		Vcc = Max.	VIN = VCC	_	110	140	
		CL = 15pF	VIN = GND				
		All Outputs Toggling	VIN = VCC -0.6V	_	110	140	
		fi = 166MHz	VIN = GND				

NOTES:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 3.3V, +25°C ambient.

3. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.

- 4. IC = IQUIESCENT + INPUTS + IDYNAMIC
- $IC = ICC + \Delta ICC DHNT + ICCD$ (fi)
 - Icc = Quiescent Current
- ΔIcc = Power Supply Current for a TTL High Input (VIN = Vcc -0.6V)
- DH = Duty Cycle for TTL Inputs High
- NT = Number of TTL Inputs at DH
- ICCD = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)
- fi = Input Frequency

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified

Industrial: TA = -40° C to $+85^{\circ}$ C, Vcc = 3.3V ± 0.3 V

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
Vін	Input HIGH Level			2	—	5.5	V
VIL	Input LOW Level			-0.5	_	0.8	V
Іін	Input HIGH Current	Vcc = Max.	VI = 5.5V	—	—	±1	μA
lıL	Input LOW Current	Vcc = Max.	VI = GND	—	_	±1	
Vik	Clamp Diode Voltage	Vcc = Min., IIN = -18mA		—	-0.7	-1.2	V
Іодн	Output HIGH Current	$V\text{CC} = 3.3\text{V}, \text{VIN} = \text{VIH or VIL}, \text{ VO} = 1.5\text{V}^{(3,4)}$		-45	-75	-180	mA
IODL	Output LOW Current	$VCC = 3.3V, VIN = VIH \text{ or } VIL, VO = 1.5V^{(3,4)}$		50	92	200	mA
los	Short Circuit Current	$VCC = Max., VO = GND^{(3,4)}$		-60	-135	240	mA
Vон	Output HIGH Voltage	Vcc = Min.	IOH = —12mA	2.4 ⁽⁵⁾	3	_	V
		VIN = VIH or VIL	Iон = -100µА	Vcc-0.2	—	—	
Vol	Output LOW Voltage	Vcc = Min.	IOL = 12mA	_	0.3	0.5	V
		VIN = VIH or VIL	IOL = 100µA	_	_	0.2	

NOTES:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 3.3, 25°C ambient.

3. This parameter is guaranteed but not tested.

4. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.

5. VoH = Vcc - 0.6V at rated current.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE (3,4)

Symbol	Parameter	Conditions ^(1,8)	Min. ⁽²⁾	Max.	Unit
tPLH	Propagation Delay	C∟ = 15pF	0.5	3	ns
t PHL		f ≤166MHz			
tR	Output Rise Time (0.8V to 2V)		—	1.5	ns
tF	Output Fall Time (2V to 0.8V)		_	1.5	ns
tSK(O)	Same device output pin-to-pin skew ⁽⁵⁾		—	100	ps
tSK(P)	Pulse skew ⁽⁶⁾		_	250	ps
tSK(PP)	Part to part skew ⁽⁷⁾		_	550	ps
fMAX	Input Frequency		_	166	MHz

NOTES:

1. See test circuits and waveforms.

2. Minimum limits are guaranteed but not tested on Propagation Delays.

3. tPLH, tPHL, tsk(P), and tsk(o) are production tested. All other parameters guaranteed but not production tested.

4. Propagation delay range indicated by Min. and Max. limit is due to Vcc, operating temperature and process parameters. These propagation delay limits do not imply skew. 5. Skew measured between all outputs under identical transitions and load conditions.

6. Skew measured is difference between propagation delay times tPHL and tPLH of same output under identical load conditions.

7. Part to part skew for all outputs given identical transitions and load conditions at identical Vcc levels and temperature.

8. Airflow of 1m/s is recommended for frequencies above 133MHz.

TEST CIRCUITS

TEST CONDITIONS

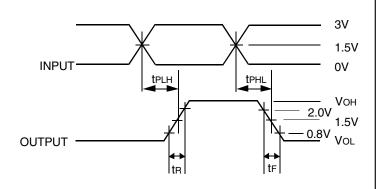
Symbol	Symbol Vcc = 3.3V ±0.3V	
CL 15		pF
RL 33		Ω
RT ZOUT of pulse generator		Ω
tR / tF 1 (0V to 3V or 3V to 0V)		ns

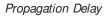
DEFINITIONS:

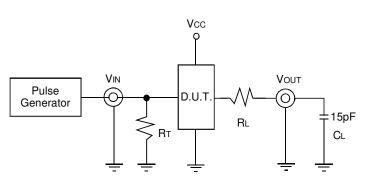
 C_{L} = Load capacitance: includes jig and probe capacitance.

 $R\tau$ = Termination resistance: should be equal to Zout of the Pulse Generator. th / tF = Rise/Fall time of the input stimulus from the Pulse Generator.

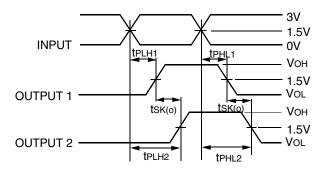






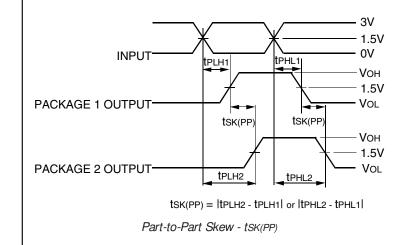






tSK(o) = |tPLH2 - tPLH1| or |tPHL2 - tPHL1|

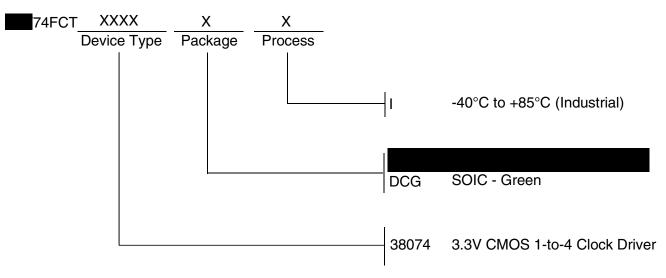
Output Skew - tSK(O)





Part-to-Part Skew is for the same package and speed grade.

ORDERINGINFORMATION



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